

PT370/PT371/PT372Compact, Stem Type
PhototransistorT-41-61
T-41-03■ **Features**

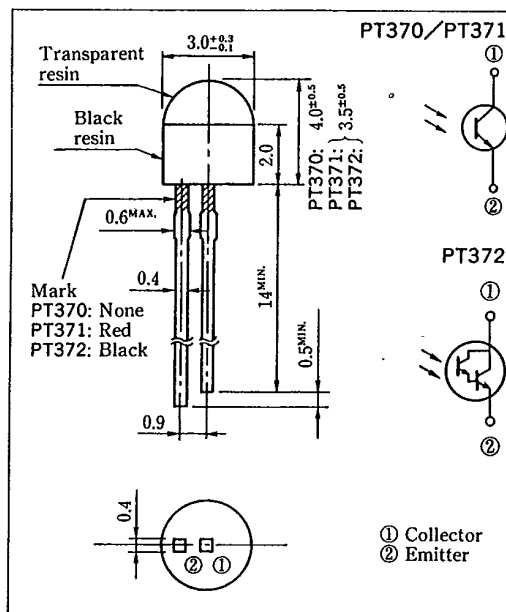
1. $\phi 3\text{mm}$ compact, resin stem type
2. Acceptance PT370 $\Delta \theta$: TYP. $\pm 45^\circ$
PT371 $\Delta \theta$: TYP. $\pm 65^\circ$
PT372 $\Delta \theta$: TYP. $\pm 70^\circ$
3. Single phototransistor output: PT370/
PT371
Darlington phototransistor output: PT372

■ **Applications**

1. Floppy disk drives
2. VCRs,
3. Automatic stroboscopes
4. Optoelectronic switches, optoelectronic counters

■ **Outline Dimensions**

(Unit : mm)

■ **Absolute Maximum Ratings**

(Ta = 25°C)

Parameter	Symbol	Rating	Unit
Collector-emitter voltage	V_{CEO}	35	V
Emitter-collector voltage	V_{ECO}	6	V
Collector current	I_C	20	mA
		50	
Collector power dissipation	P_C	75	mW
Operating temperature	T_{opr}	-25 ~ +85	°C
Storage temperature	T_{stg}	-25 ~ +85	°C
*1 Soldering temperature	T_{sol}	260	°C

*1 For 3 seconds at the position of 1.5mm from the bottom face of resin package

SHARP

T-41-61

■ Electro-optical Characteristics

T-41-63

(T_a=25°C)

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
*2 Collector current	PT370	*3 E _v =100lx, V _{CE} =5V (PT372: V _{CE} =2V)	100	300	900	μA
	PT371		100	—	900	
	PT372		3.0	—	23	mA
Collector dark current	PT370/PT371	E _e =0, V _{CE} =20V	—	2.0	100	nA
	PT372	E _e =0, V _{CE} =10V	—	—	1.0	μA
Collector-emitter saturation voltage	PT370/PT371	*3 E _e =10mW/cm ² , I _C =0.5mA	—	0.2	0.4	V
	PT372	*3 E _e =1mW/cm ² , I _C =2.5mA	—	0.8	1.0	
Peak sensitivity wavelength	λ _p	—	—	800	—	nm
Response time (Rise)	PT370/PT371	V _{CC} =20V, I _C =1mA, R _L =1kΩ	—	10	40	μs
	PT372	V _{CE} =2V, I _C =10mA, R _L =100Ω	—	100	400	μs
Response time (Fall)	PT370/PT371	V _{CC} =20V, I _C =1mA, R _L =1kΩ	—	8	35	μs
	PT372	V _{CE} =2V, I _C =10mA, R _L =100Ω	—	100	400	μs
Half intensity angle	PT370	—	—	±45	—	deg.
	PT371		—	±65	—	
	PT372		—	±70	—	

*2 The collector current (I_C) shall be classified into the ranks as follows before delivery.

Rank	Collector current I _C		
	PT370 (μA)	PT371 (μA)	PT372 (mA)
A	100~216	100~244	3.0~9.66
B	170~320	192~463	7.14~23.0
C	252~533	363~900	—
D	419~900	—	—

*3 E_v, E_e: Illuminance, irradiance by CIE standard light source A (tungsten lamp)

Fig. 1 Collector Power Dissipation vs. Ambient Temperature

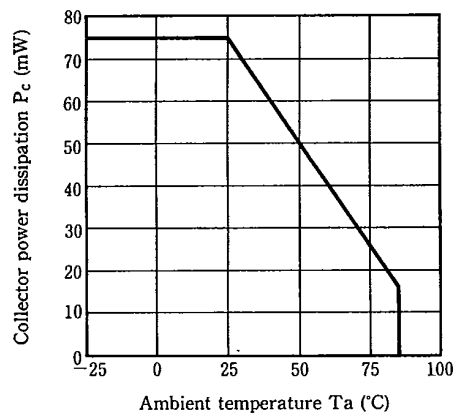
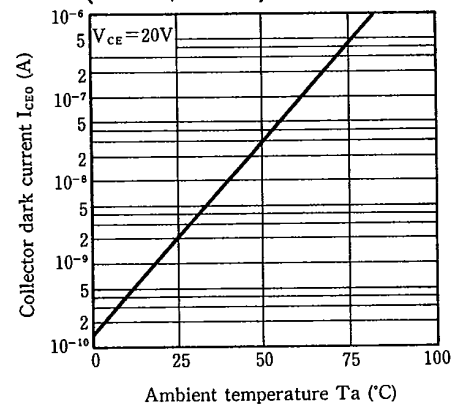


Fig. 2 Collector Dark Current vs. Ambient Temperature (PT370/PT371)



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Fig. 3 Collector Dark Current vs. Ambient Temperature (PT372)

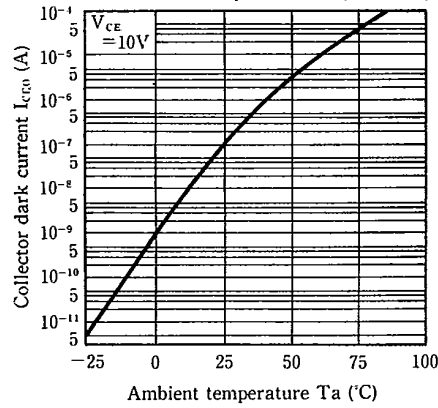


Fig. 4 Relative Collector Current vs. Ambient Temperature (PT370/PT371)

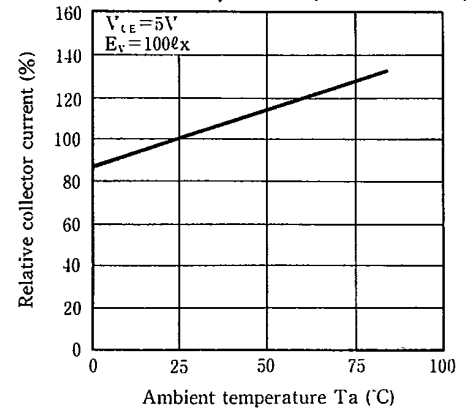


Fig. 5 Relative Collector Current vs. Ambient Temperature (PT372)

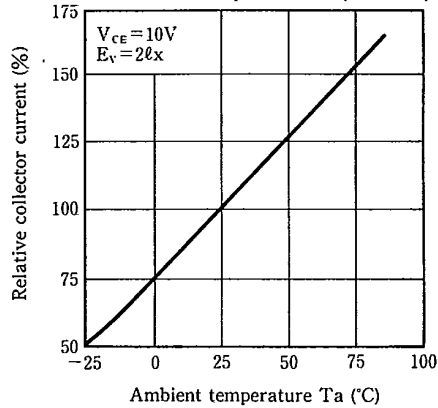


Fig. 6 Collector Current vs. Irradiance (PT370/PT371)

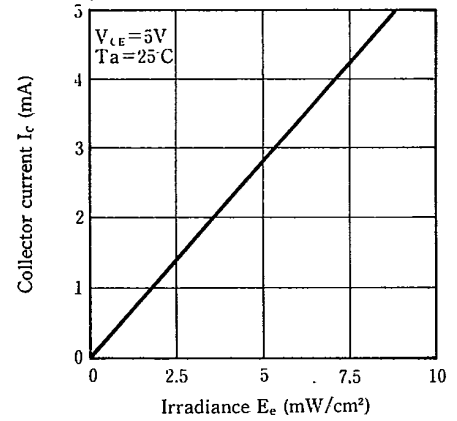


Fig. 7 Collector Current vs. Irradiance (PT372)

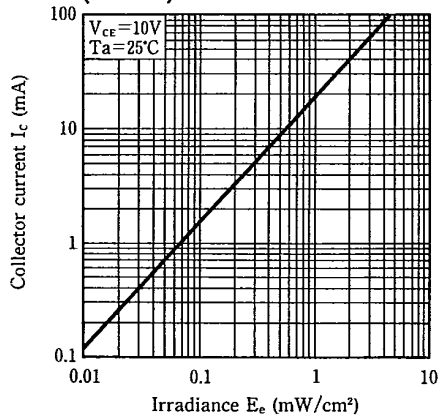


Fig. 8 Collector Current vs. Collector-emitter Voltage (PT370)

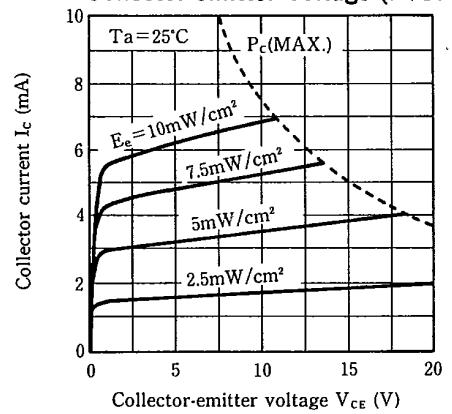


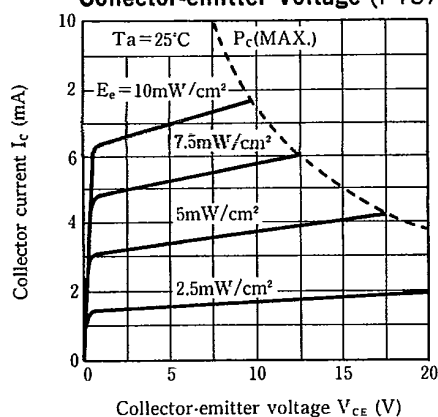
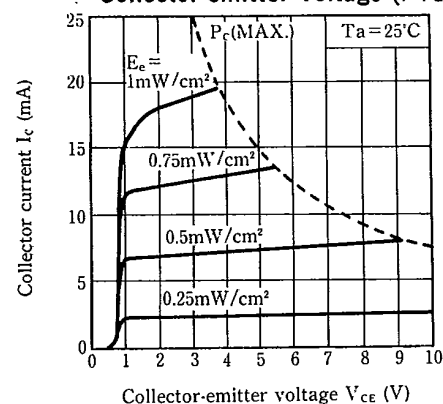
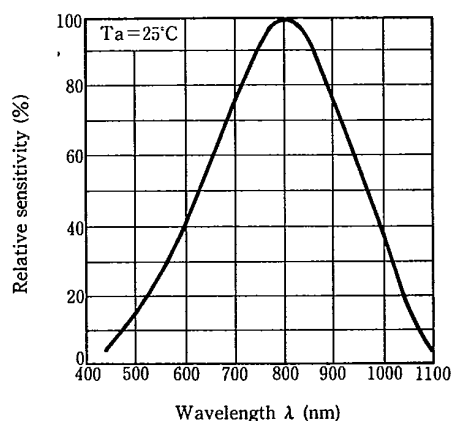
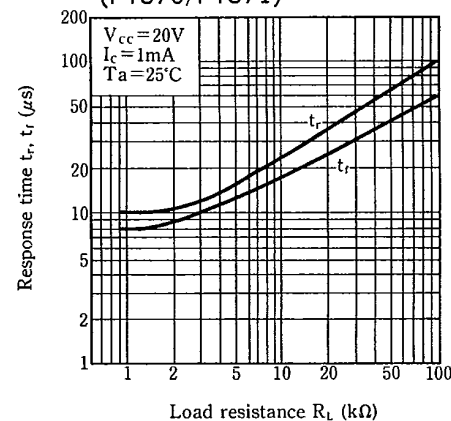
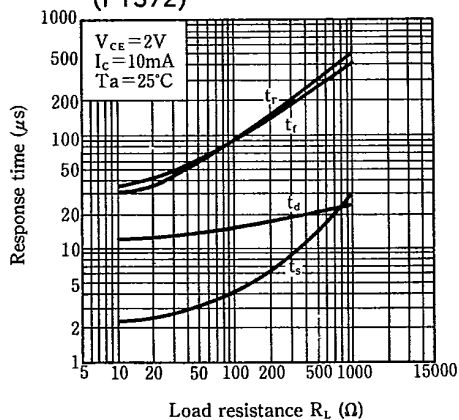
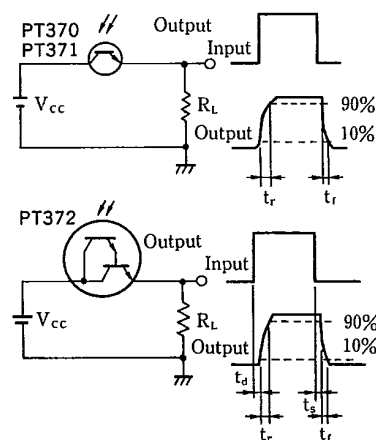
Fig. 9 Collector Current vs. Collector-emitter Voltage (PT371)**Fig. 10 Collector Current vs. Collector-emitter Voltage (PT372)****Fig. 11 Spectral Sensitivity****Fig. 12 Response Time vs. Load Resistance (PT370/PT371)****Fig. 13 Response Time vs. Load Resistance (PT372)****Test Circuit for Response Time**

Fig. 14 Sensitivity Diagram (PT370)
($T_a = 25^\circ\text{C}$)

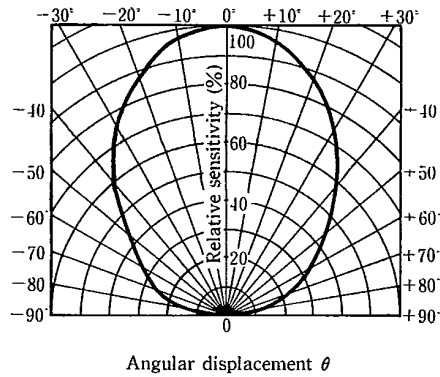


Fig. 15 Sensitivity Diagram (PT371)
($T_a = 25^\circ\text{C}$)

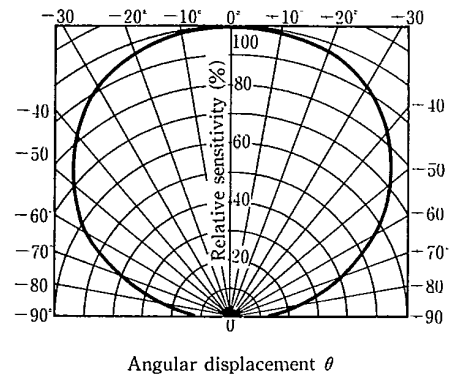


Fig. 16 Sensitivity Diagram (PT372)
($T_a = 25^\circ\text{C}$)

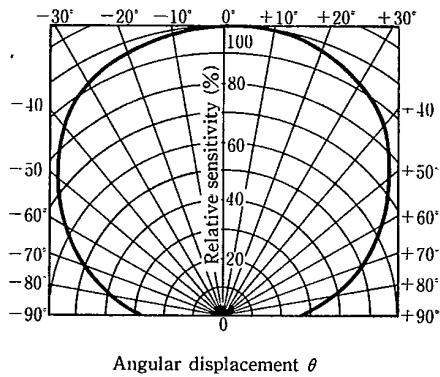


Fig. 17 Collector-emitter Saturation Voltage vs. Irradiance (PT370)

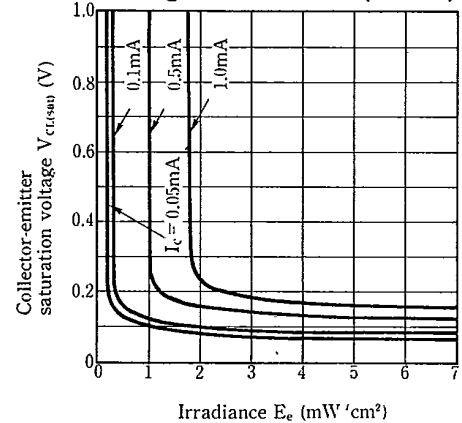


Fig. 18 Collector-emitter Saturation Voltage vs. Irradiance (PT371)

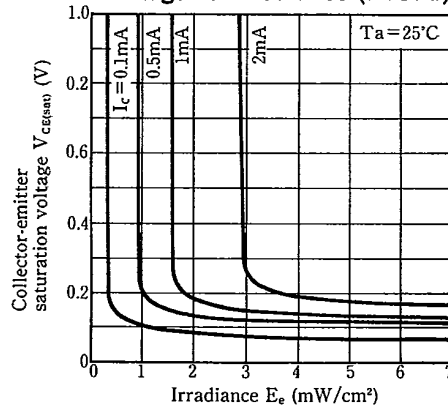


Fig. 19 Collector-emitter Saturation Voltage vs. Irradiance (PT372)

